Data sheet acquired from Harris Semiconductor SCHS211E

High-Speed CMOS Logic

8-Stage Shift and Store Bus Register, Three-State November 1997 – Revised December 2010

Features

- ¥ Buffered Inputs
- ¥ Separate Serial Outputs Synchronous to Both Positive and Negative Clock Edges For Cascading
- **¥ Fanout (Over Temperature Range)**
- Standard Outputs......10 LSTTL Loads - Bus Driver Outputs15 LSTTL Loads
- ¥ Wide Operating T emperature Rang e . . . -55°C to 125°C
- ¥ Balanced Propagation Delay and Transition Times
- ¥ Signi Cant Power Reduction Compared to LSTTL Logic ICs
- **¥ HC Types**
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at $V_{CC} = 5V$

¥ HCT Types

- 4.5V to 5.5V Operation
- Direct LSTTL Input Logic Compatibility, V_{IL} = 0.8V (Max), V_{IH} = 2V (Min)
- CMOS Input Compatibility, I_I \leq 1 μ A at V_{OL}, V_{OH}

Description

The ÕHC4094and CD74HCT4094 are 8-stage serial shift registers having a storage latch associated with each stage for strobing data from the serial input to parallel buffered three-state outputs. The parallel outputs may be connected directly to common bus lines. Data is shifted on positive clock transitions. The data in each shift register stage is transferred to the storage register when the Strobe input is high. Data in the storage register appears at the outputs whenever the Output-Enable signal is high.

Two serial outputs are available for cascading a number of these devices. Data is available at the ${\sf QS}_1$ serial output terminal on positive clock edges to allow for high-speed operation in cascaded system in which the clock rise time is fast. The same serial information, available at the QS2 terminal on the next negative clock edge, provides a means for cascading these devices when the clock rise time is slow.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4094F3A	-55 to 125	16 Ld CERDIP
CD74HC4094E	-55 to 125	16 Ld PDIP
CD74HC4094M	-55 to 125	16 Ld SOIC
CD74HC4094MT	-55 to 125	16 Ld SOIC
CD74HC4094M96G3	-55 to 125	16 Ld SOIC
CD74HC4094NSR	-55 to 125	16 Ld SOP
CD74HC4094PW	-55 to 125	16 Ld TSSOP
CD74HC4094PWR	-55 to 125	16 Ld TSSOP
CD74HC4094PWT	-55 to 125	16 Ld TSSOP
CD74HCT4094E	-55 to 125	16 Ld PDIP
CD74HCT4094M	-55 to 125	16 Ld SOIC
CD74HCT4094MT	-55 to 125	16 Ld SOIC
CD74HCT4094M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suf esses 96 and R denote tape and reel. The suf Lx T denotes a small-quantity reel of 250.

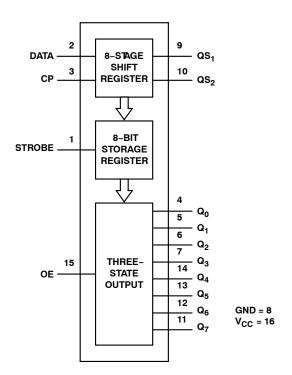
Pinout

CD54HC4094 (CERDIP) CD74HC4094 (PDIP, SOIC, SOP, TSSOP) CD74HCT4094 (PDIP, SOIC)

TOP VIEW STROBE 1 16 V_{CC} 15 OE DATA 2 14 Q₄ CP 3 13 Q₅ 12 Q₆ Q₁ 5 $Q_2 = 6$ 11 Q₇ 10 QS₂ 9 QS₁ GND 8

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures. Copyright 🗓 2003, Texas Instruments Incorporated

Functional Diagram



TRUTH TABLE

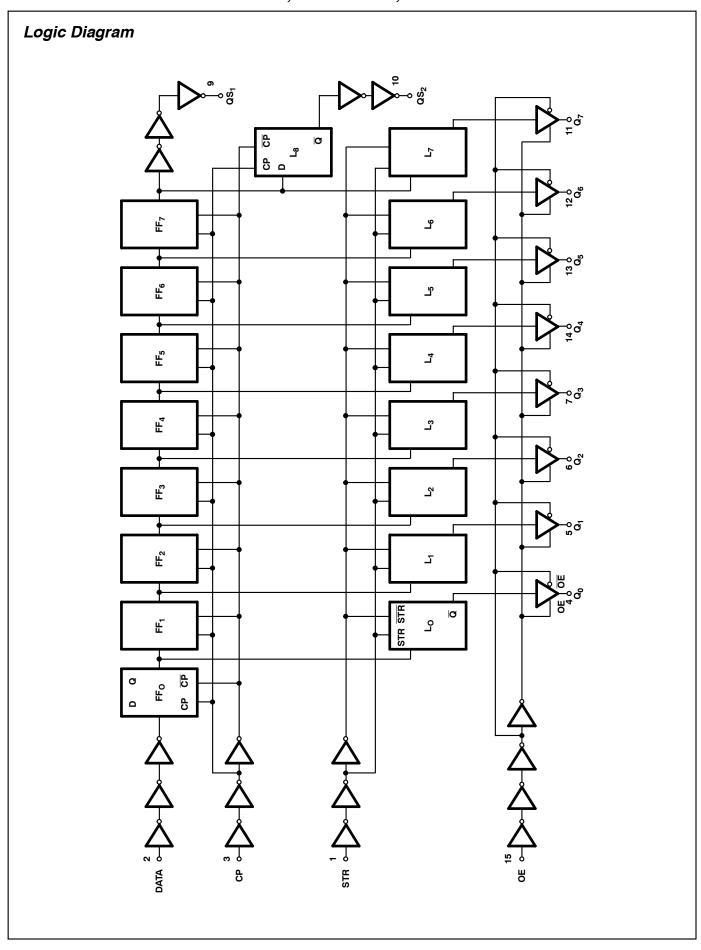
	INPU	ITS		PARALLEL	OUTPUTS	SERIAL OUTPUTS		
СР	OE	STR	D	Q ₀	Q _n	QS ₁ (NOTE 1)	QS ₂	
1	L	Х	Х	Z	Z	QÕ6	NC	
↓	L	Х	Х	Z	Z	NC	Q ₇	
1	Н	L	Х	NC	NC	QÕ6	NC	
1	Н	Н	L	L	Q _n –1	QÕ6	NC	
1	Н	Н	Н	Н	Q _n –1	QÕ6	NC	
<u> </u>	Н	Н	Н	NC	NC	NC	Q ₇	

H = High Voltage Level, L = Low Voltage Level, X = DonÕt Care, NC = No charge, Z = High Impedance Off-state,

↑ = Transition from Low to High Level, ↓ = Transition from High to Low.

NOTE:

1. At the positive clock edge the information in the seventh register stage is transferred to the 8th register stage and QS1 output.



Thermal Information

Package Thermal Impedance, θ_{JA} (see Note 2):
E (PDIP) Package
M (SOIC) Package73°C/W
NS (SOP) Package
PW (TSSOP) Package
Maximum Junction Temperature (Plastic Package) 150°
Maximum Storage Temperature Range65°C to 150°
Maximum Lead Temperature (Soldering 10s)300°
SOIC - Lead Tips Only)

Operating Conditions

CAUTION: Stresses above those listed in OAbsoluteMaximum RatingsÓnay cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Speci ¿cations

		TES CONDI		v _{cc}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES												
High Level Input	V _{IH}	-	-	2	1.5	ı	-	1.5	-	1.5	_	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	_	٧
				6	4.2	1	-	4.2	_	4.2	_	>
Low Level Input	V _{IL}	-	-	2	-	-	0.5	_	0.5	_	0.5	V
Voltage				4.5	_	-	1.35	-	1.35	-	1.35	V
				6	_	-	1.8	_	1.8	_	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	_	1.9	_	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	_	V
omeo Loddo			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads		,	-4	4.5	3.98	-	-	3.84	-	3.7	-	V
TTE Educa			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
OWIGO Educa			0.02	6	_	-	0.1	-	0.1	-	0.1	V
Low Level Output	7		-	-	_	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
112 20003			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	IĮ	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	lcc	V _{CC} or GND	0	6	-	ı	8	-	80	-	160	μА

DC Electrical Speci¿cations (Continued)

		TES CONDI		V _{CC}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	V _{IH}	_	-	4.5 to 5.5	2	-	-	2	_	2	-	٧
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	=	3.7	=	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	I _I	V _{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μА
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	ΔI _{CC} (Note 3)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μА

NOTE:

HCT Input Loading Table

INPUT	UNIT LOADS
D	0.4
CP, OE	1.5
STR	1.0

NOTE: Unit Load is ΔI_{CC} limit speci@ed in DC Electrical Table, e.g., 360µA max at 25°C.

Prerequisite for Switching Speci∂cations

			25	°C	-40°C T	O 85°C	-55°C T		
CHARACTERISTIC	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES									
CP Pulse Width	t _W	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
STR Pulse Width	t _{WH}	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	_	ns

^{3.} For dual-supply systems theoretical worst case (γ = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

Prerequisite for Switching Speci@cations (Continued)

			25	5°C	-40°C 1	ΓΟ 85°C	-55°C T	O 125°C	
CHARACTERISTIC	SYMBOL	V _{CC} (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Data Set-up Time	t _{SU}	2	50	-	65	-	75	-	ns
		4.5	10	-	13	-	15	-	ns
		6	9	-	11	-	13	-	ns
Data Hold Time	t _H	2	3	-	3	-	3	-	ns
		4.5	3	-	3	-	3	-	ns
		6	3	-	3	-	3	-	ns
STR Set-up Time	t _{SU}	2	100	-	125	-	150	-	ns
		4.5	20	-	25	_	30	_	ns
		6	17	-	21	-	26	-	ns
STR Hold Time	t _H	2	0	-	0	-	0	-	ns
		4.5	0	-	0	-	0	-	ns
		6	0	-	0	-	0	_	ns
Maximum CP Frequency	f _{CL (MAX)}	2	6	-	5	-	4	_	MHz
		4.5	30	-	24	-	20	_	MHz
		6	35	-	28	-	24	_	MHz
HCT TYPES	•		•		•	•	•		•
CP Pulse Width	t _W	4.5	16	-	20	-	24	-	ns
STR Pulse Width	t _{WH}	4.5	16	-	20	-	24	_	ns
Data Set-up Time	t _{SU}	4.5	10	-	13	-	15	-	ns
Data Hold Time	t _H	4.5	4	-	4	-	4	-	ns
STR Set-up Time	t _{SU}	4.5	20	-	25	-	30	-	ns
STR Hold Time	t _H	4.5	0	-	0	-	0	-	ns
Maximum CP Frequency	f _{CL (MAX)}	4.5	30	-	24	-	20	-	MHz

Switching Speci \cite{l} cations Input t_r , t_f = 6ns

		TEST	v _{cc}		25°C		-40°C T	O 85°C	–55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES											
Propagation Delay Time (Figure 1)	t _{PLH,} t _{PHL}	C _L = 50pF	2	-	-	150	-	190	-	225	ns
CP to QS ₁			4.5	-	-	30	-	38	-	45	ns
		C _L =15pF	5	-	12	_	-	_	-	_	ns
		C _L = 50pF	6	-	-	26	-	33	-	38	ns
CP to QS ₂	t _{PLH} ,	C _L = 50pF	2	-	-	135	-	170	-	205	ns
	t _{PHL}		4.5	-	-	27	-	34	-	41	ns
		C _L =15pF	5	-	11	-	-	_	-	_	ns
		C _L = 50pF	6	-	-	23	-	29	-	35	ns
CP to Q _n	t _{PLH} ,	C _L = 50pF	2	-	-	195	-	245	-	295	ns
	t _{PHL}		4.5	-	-	39	-	49	-	59	ns
			5	-	16	-	-	_	-	_	ns
			6	-	-	33	-	42	-	50	ns
STR to Q _n	t _{PLH} ,	C _L = 50pF	2	-	-	180	-	225	-	270	ns
	t _{PHL}		4.5	-	-	36	-	45	-	54	ns
			6	-	-	31	_	38	_	46	ns

Switching Speci $\cite{locations}$ Input t_r , t_f = 6ns (Continued)

		TEST	v _{cc}		25°C		_40°C T	O 85°C	–55°C T	O 125°C	
PARAMETER	SYMBOL	CONDITIONS	(S)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Output Enable to Q _n	t _{PZH} , t _{PZL}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
]	4.5	-	-	35	-	44	-	53	ns
]	6	-	_	30	-	37	-	45	ns
Output Disable to Qn	t _{PHZ} , t _{PLZ}	C _L = 50pF	2	-	-	125	-	155	-	190	ns
			4.5	-	-	25	-	31	-	38	ns
			6	-	-	21	-	26	-	32	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	_	75	-	95	-	110	ns
]	4.5	-	-	15	-	19	-	22	ns
]	6	-	-	13	-	16	-	19	ns
Output Disabling Time	t _{PHZ} , t _{PLZ}	C _L =15pF	5	-	10	_	-	-	-	-	ns
Maximum CP Frequency	f _{MAX}	C _L =15pF	5	-	60	_	-	-	-	-	MHz
Input Capacitance	C _{IN}	C _L = 50pF	_	-	_	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	C _L =15pF	5	-	90	-	-	-	-	-	pF
Three-State Output Capacitance	Co	C _L = 50pF	-	-	-	15	-	15	-	15	pF
HCT TYPES											
Propagation Delay Time (Figure 1)	t _{PLH,} t _{PHL}	C _L = 50pF	4.5	_	-	39	-	-	-	_	ns
CP to QS ₁		C _L =15pF	5	-	16	_	-	-	-	-	ns
CP to QS ₂	t _{PLH} ,	C _L = 50pF	4.5	-	-	36	-	-	-	-	ns
	t _{PHL}	C _L =15pF	5	-	15	_	-	-	-	-	ns
CP to Q _n	t _{PLH} ,	C _L = 50pF	4.5	-	-	43	-	-	-	-	ns
	t _{PHL}	C _L =15pF	5	-	18	-	-	_	-	-	ns
STR to Q _n	t _{PLH,} t _{PHL}	C _L = 50pF	4.5	-	-	39	-	-	-	-	ns
Output Enable to Q _n	t _{PZH} , t _{PZL}	C _L = 50pF	4.5	-	-	35	-	_	-	_	ns
Output Disable to Q _n	t _{PHZ} , t _{PLZ}	C _L = 50pF	4.5	-	_	35	_	-	-	-	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	4.5	-	-	15	-	-	-	_	ns
Output Disabling Time	t _{PHZ} , t _{PLZ}	C _L =15pF	5	-	14	_	-	-	-	-	ns
Maximum CP Frequency	f _{MAX}	C _L =15pF	5	-	60	_	-	-	-	-	MHz
Input Capacitance	C _{IN}	C _L = 50pF	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	C _L =15pF	5	_	110	-	-	-	-	-	pF
Three-State Output Capacitance	C _O	C _L = 50pF	-	-	-	15	-	15	-	15	pF

^{4.} $C_{\mbox{PD}}$ is used to determine the dynamic power consumption, per register.

^{5.} $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage.

CD54/74HC4094, CD74HCT4094

Test Circuits and Waveforms

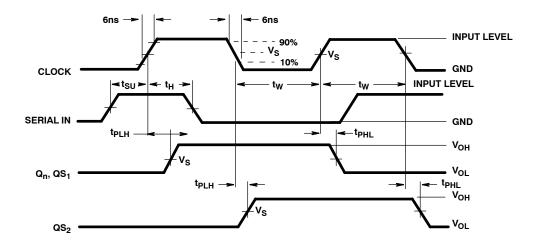
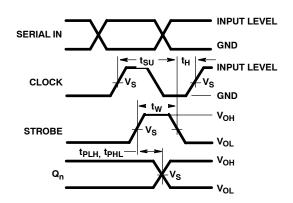


FIGURE 1. DATA PROPAGATION DELAYS, SET-UP AND HOLD TIMES



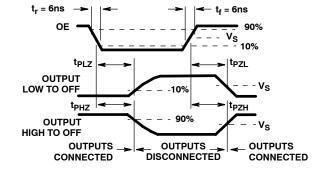


FIGURE 2. STROBE PROPAGATION DELAYS AND SET-UP AND HOLD TIMES

FIGURE 3. ENABLE AND DISABLE TIMES





23-Aug-2017

PACKAGING INFORMATION

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD54HC4094F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HC4094F3A	Samples
CD74HC4094E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC4094E	Samples
CD74HC4094M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094M96G3	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094NSR	ACTIVE	SO	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094NSRE4	ACTIVE	so	NS	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4094M	Samples
CD74HC4094PW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4094	Samples
CD74HC4094PWG4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4094	Samples
CD74HC4094PWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-55 to 125	HJ4094	Samples
CD74HC4094PWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4094	Samples
CD74HC4094PWRG4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HJ4094	Samples
CD74HCT4094E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4094E	Samples
CD74HCT4094EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT4094E	Samples



PACKAGE OPTION ADDENDUM

23-Aug-2017

Orderable Device	Status	Package Type	_	Pins	_	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
CD74HCT4094M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4094M	Samples
CD74HCT4094M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-55 to 125	HCT4094M	Samples
CD74HCT4094ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT4094M	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.





23-Aug-2017

OTHER QUALIFIED VERSIONS OF CD54HC4094, CD74HC4094:

● Catalog: CD74HC4094

Military: CD54HC4094

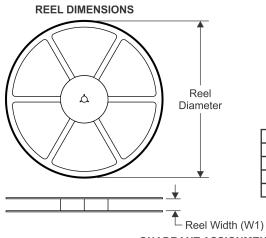
NOTE: Qualified Version Definitions:

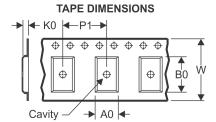
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

www.ti.com 24-Aug-2017

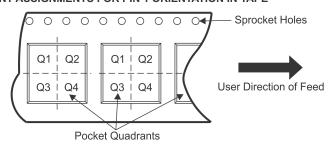
TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4094M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4094M96	SOIC	D	16	2500	330.0	16.8	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4094M96G3	SOIC	D	16	2500	330.0	16.8	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4094M96G4	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
CD74HC4094NSR	SO	NS	16	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
CD74HC4094PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4094PWR	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HC4094PWRG4	TSSOP	PW	16	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
CD74HCT4094M96	SOIC	D	16	2500	330.0	16.8	6.5	10.3	2.1	8.0	16.0	Q1
CD74HCT4094M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1

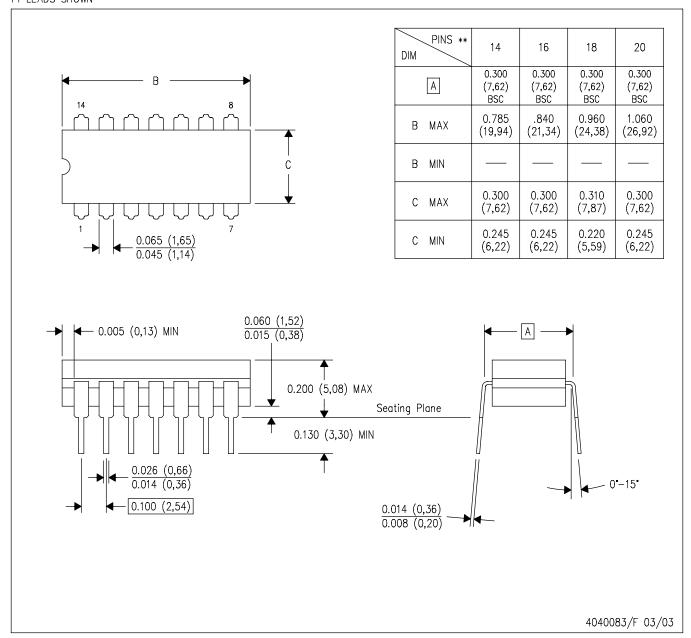
www.ti.com 24-Aug-2017



*All dimensions are nominal

Device	Device Package Type		Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
CD74HC4094M96	SOIC	D	16	2500	333.2	345.9	28.6	
CD74HC4094M96	SOIC	D	16	2500	364.0	364.0	27.0	
CD74HC4094M96G3	SOIC	D	16	2500	364.0	364.0	27.0	
CD74HC4094M96G4	SOIC	D	16	2500	333.2	345.9	28.6	
CD74HC4094NSR	SO	NS	16	2000	367.0	367.0	38.0	
CD74HC4094PWR	TSSOP	PW	16	2000	364.0	364.0	27.0	
CD74HC4094PWR	TSSOP	PW	16	2000	367.0	367.0	35.0	
CD74HC4094PWRG4	TSSOP	PW	16	2000	367.0	367.0	35.0	
CD74HCT4094M96	SOIC	D	16	2500	364.0	364.0	27.0	
CD74HCT4094M96	SOIC	D	16	2500	333.2	345.9	28.6	

14 LEADS SHOWN

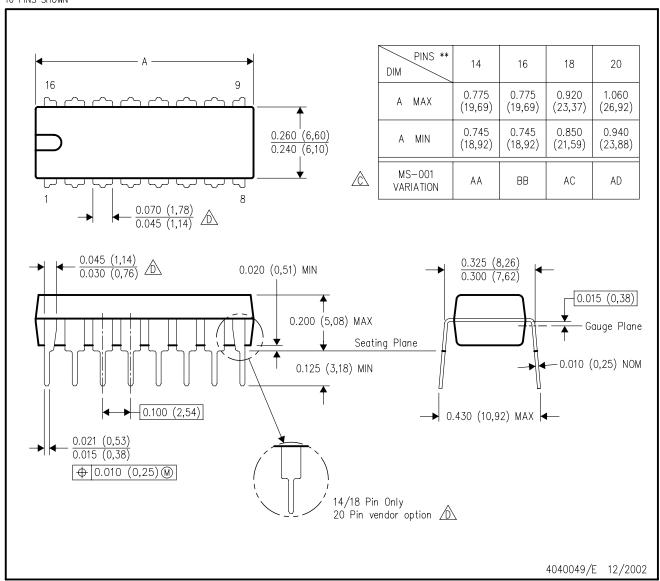


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE

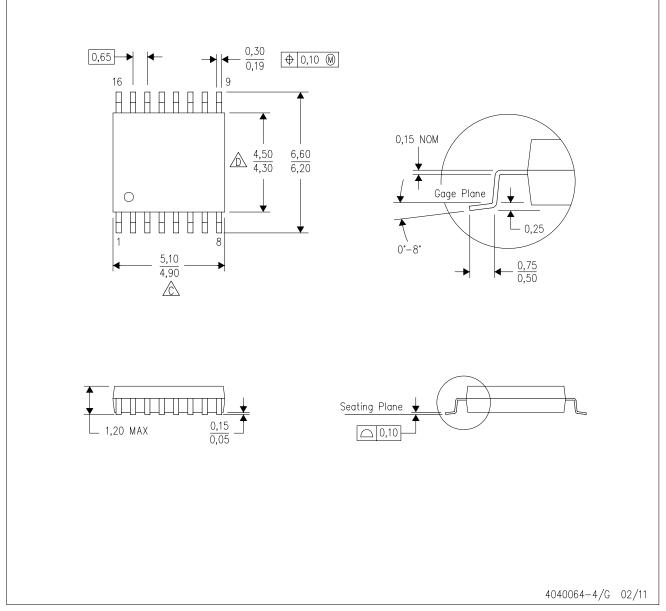


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE

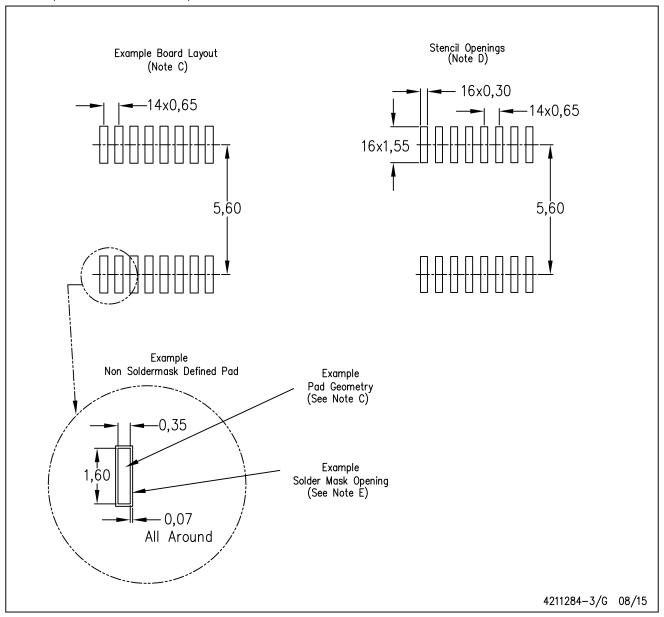


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G16)

PLASTIC SMALL OUTLINE



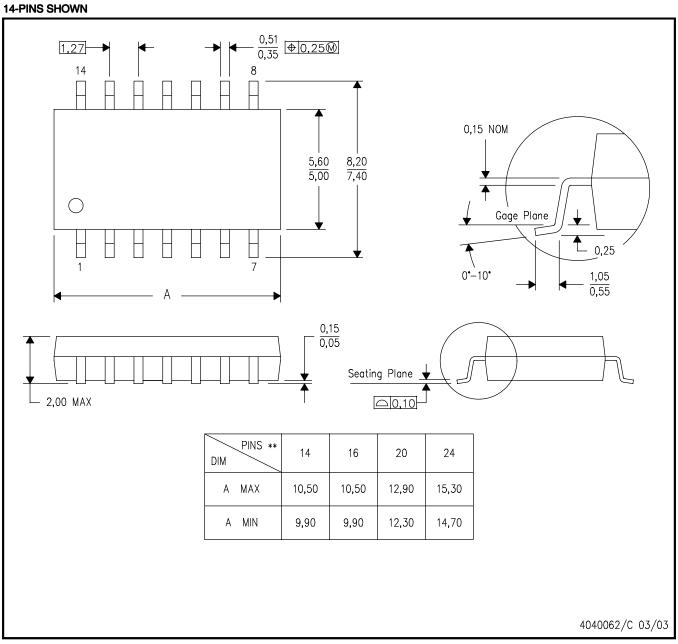
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE



- All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



IMPORTANT NOTICE

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (http://www.ti.com/sc/docs/stdterms.htm) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.